

(FIELD-EFFECT TRANSISTOR)

2SK433

FOR LOW FREQUENCY AMPLIFY APPLICATION
N CHANNEL JUNCTION TYPE

DESCRIPTION

2SK433 is a super mini outline resin sealed silicon N channel junction type FET. It is designed for low frequency voltage amplify, application, analog switch application.

FEATURE

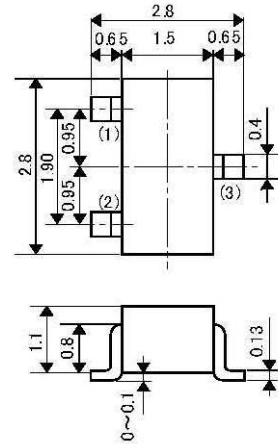
- Small type for mounting
- High $|y_{fs}|$ $|y_{fs}| = 4\text{mS}(\text{typ})$
- Low $R_{DS(ON)}$ $R_{DS(ON)} = 250\Omega$ typ

APPLICATION

General purpose voltage amplify, analog switch circuit for stereo, cassette deck, VCR.

OUTLINE DRAWING

Unit:mm



TERMINAL CONNECTOR

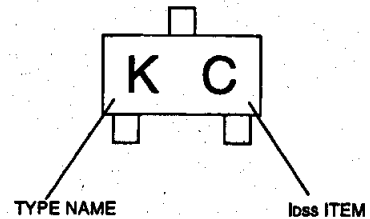
- ① : SOURCE
 - ② : DRAIN
 - ③ : GATE
- EIAJ : SC-59
JEDEC : TO-236 resemblance

Note)
The dimension without tolerance represent central value.

MAXIMUM RATINGS (Ta=25°C)

Symbol	Parameter	Ratings	Unit
V _{GDO}	Gate to Drain voltage	-50	V
I _G	Gate current	10	mA
P _T	Total allowable dissipation(Ta=25°C)	150	mW
T _{ch}	Channel temperature	+125	°C
T _{stg}	Storage temperature	-55 to +125	°C

MARKING



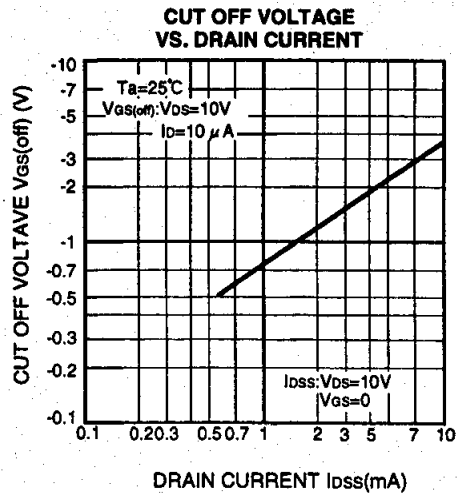
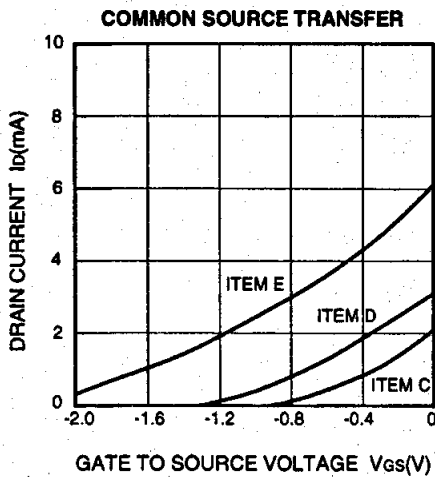
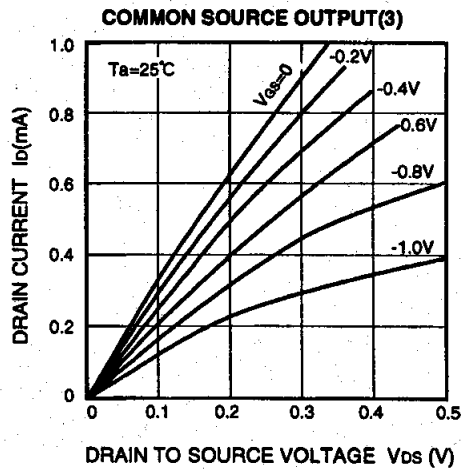
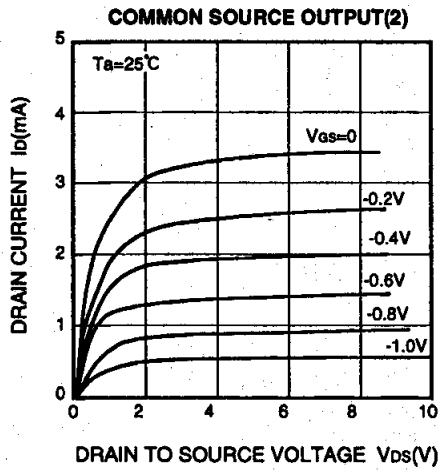
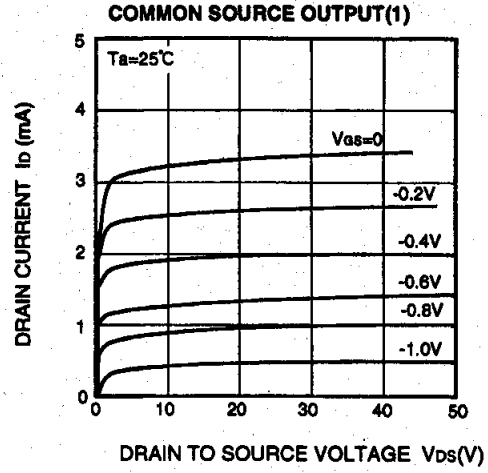
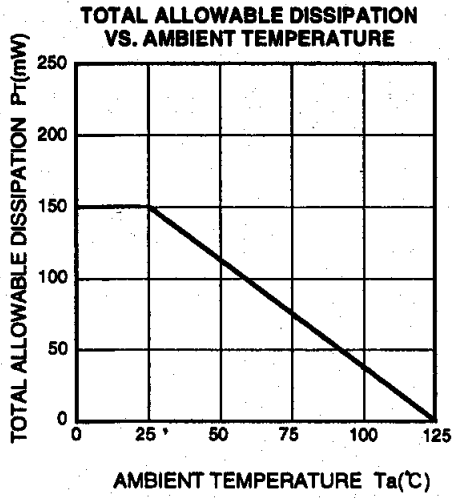
ELECTRICAL CHARACTERISTICS (Ta=25°C)

Symbol	Parameter	Test conditions	Limits			Unit
			Min	Typ	Max	
V _{(BR)GDO}	G to D break down voltage	I _G =-10μA, I _S =0	-50			V
I _{GSS}	Gate leakage current	V _{GS} =-30V, V _{DS} =0			-1	nA
I _{DSS*}	Drain current	V _{DS} =10V, V _{GS} =0	0.6		12	mA
V _{GS(off)}	Cut off voltage	V _{DS} =10V, I _D =10μA	-0.3	-1.5	-6.0	V
y _{fs}	Forward transfer admittance	V _{DS} =10V, V _{GS} =0, f=1kHz	1.0	3.0		mS
y _{os}	Output admittance	V _{DS} =10V, V _{GS} =0, f=1kHz		10		μS
C _{iss}	Input capacitance	V _{DS} =10V, V _{GS} =0, f=1MHz		8		pF
C _{rss}	Feed back capacitance	V _{DS} =10V, V _{GS} =0, f=1MHz		1.5		pF
R _{DS(ON)}	Drain to source resistor	V _{DS} =10mVrms(1kHz), V _{GS} =0, I _{DSS} =5mA		250		Ω

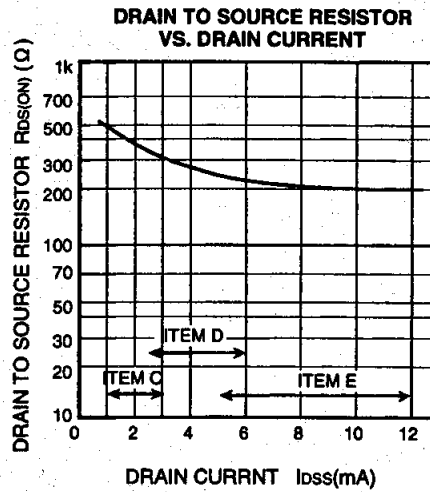
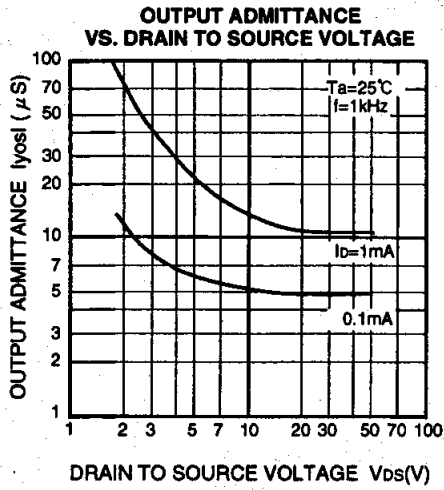
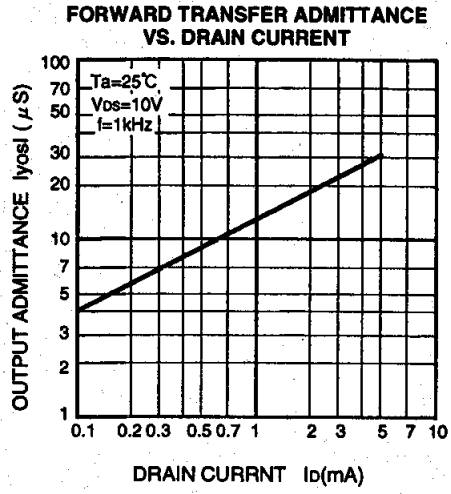
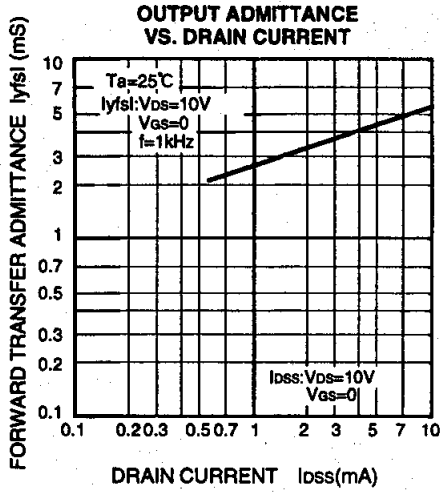
* : It shows loss classification in right table.

Item	B	C	D	E
loss	0.6 to 1.5	1.0 to 3.0	2.5 to 6.0	5.0 to 12

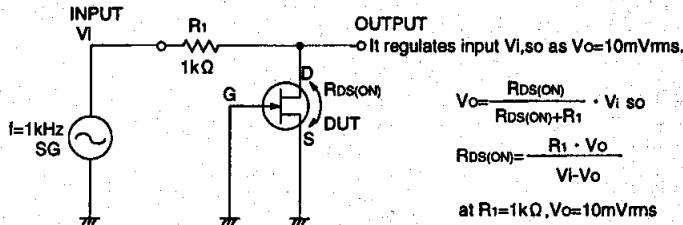
TYPICAL CHARACTERISTICS



**FOR LOW FREQUENCY AMPLIFY APPLICATION
N CHANNEL JUNCTION TYPE**



DRAIN TO SOURCE RESISTOR $R_{ds(ON)}$ TEST CIRCUIT





Marketing division, Marketing planning department

6-41 Tsukuba, Isahaya, Nagasaki, 854-0065 Japan

Keep safety first in your circuit designs!

·ISAHAYA Electronics Corporation puts the maximum effort into making semiconductor products better and more reliable, but there is always the possibility that trouble may occur with them. Trouble with semiconductors may lead to personal injury, fire or property damage. Remember to give due consideration to safety when making your circuit designs, with appropriate measures such as (1) placement of substitutive, auxiliary, (2) use of non-flammable material or (3) prevention against any malfunction or mishap.

Notes regarding these materials

- These materials are intended as a reference to our customers in the selection of the ISAHAYA products best suited to the customer's application; they don't convey any license under any intellectual property rights, or any other rights, belonging ISAHAYA or third party.
- ISAHAYA Electronics Corporation assumes no responsibility for any damage, or infringement of any third party's rights, originating in the use of any product data, diagrams, charts or circuit application examples contained in these materials.
- All information contained in these materials, including product data, diagrams and charts, represent information on products at the time of publication of these materials, and are subject to change by ISAHAYA Electronics Corporation without notice due to product improvements or other reasons. It is therefore recommended that customers contact ISAHAYA Electronics Corporation or an authorized ISAHAYA products distributor for the latest product information before purchasing product listed herein.
- ISAHAYA Electronics Corporation products are not designed or manufactured for use in a device or system that is used under circumstances in which human life is potentially at stake. Please contact ISAHAYA electronics corporation or an authorized ISAHAYA products distributor when considering the use of a product contained herein for any specific purposes, such as apparatus or systems for transportation, vehicular, medical, aerospace, nuclear, or undersea repeater use.
- The prior written approval of ISAHAYA Electronics Corporation is necessary to reprint or reproduce in whole or in part these materials.
- If these products or technologies are subject to the Japanese export control restrictions, they must be exported under a license from the Japanese government and cannot be imported into a country other than the approved destination. Any diversion or re-export contrary to the export control laws and regulations of Japan and/or the country of destination is prohibited.
- Please contact ISAHAYA Electronics Corporation or authorized ISAHAYA products distributor for further details on these materials or the products contained therein.